High-field optically detected nuclear magnetic resonance in GaAs

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A method for high-field optically detected nuclear magnetic resonance (ODNMR) is developed sensitive to 10^8 nuclei. Nuclear spin transitions are induced using a radio frequency coil and detected through Faraday rotation spectroscopy. Unlike conventional ODNMR, which is limited to low fields and relies on the measurement of time-averaged luminescence polarization, this technique monitors nuclear polarization through time-resolved measurements of electron spin dynamics. Measurements in a (110) GaAs quantum well reveal 69Ga, 71Ga, and 75As resonances and their quadrupolar splittings while resolving changes in nuclear polarization of 0.02%.

The small number of nuclear spins in quantum wells (QWs) and quantum dots makes conventional nuclear magnetic resonance (NMR) experiments difficult in these semiconductor nanostructures. Optical pumping strongly enhances nuclear spin polarization and can increase the detection sensitivity of typical radio frequency (RF) probes from a minimum of 10^17 nuclei spins to 10^12. As a result, RF detection of optically pumped GaAs multiple QWs has been achieved. Detection of NMR has also been demonstrated through optical measurements of recombination polarization, either by exciting NMR transitions with a conventional coil, or by purely optical means. In the latter case, an optical field is modulated at the nuclear Larmor frequency resulting in an oscillating electron magnetization. This magnetization interacts with nuclear spins and induces NMR transitions in an external RF field. While optically detected NMR (ODNMR) provides the high sensitivity typical of optical techniques, it has several limitations. For electron g factors and spin lifetimes typical of GaAs structures, ODNMR is only possible at low magnetic fields (<<1 T). In addition, the reliance on radiative recombination for detection makes ODNMR disproportionately sensitive to nuclei located near shallow donors and impurities.

Another type of ODNMR is possible using time-resolved Faraday rotation (FR) to probe nuclear spin polarization. In this detection scheme, FR measures the spin precession frequency of electrons in the conduction band. Nuclear spins act on electron spins through the contact hyperfine interaction altering the frequency and allowing for the precise measurement of nuclear polarization. All-optical versions of this method have been demonstrated in bulk GaAs and in a GaAs QW. These measurements can be made at high applied magnetic fields and, unlike measurements of time- and polarization-resolved photoluminescence, they are not limited by the charge recombination time.

Here we present an extension of this technique utilizing a RF coil for the excitation of NMR transitions. The use of an external a RF field allows for the future application of well-developed pulsed NMR techniques for noise reduction while at the same time exploiting the high sensitivity of FR detection. In addition, the conventional magnetic excitation of nuclear transitions circumvents the complex interactions between electrons and nuclei that take place in optical excitation schemes. Unlike conventional RF magnetic fields, which induce only dipole transitions, modulated optical fields induce both magnetic dipole transitions and electric quadrupole transitions.

As shown in Fig. 1, a semiconductor sample is cooled to T=5 K in a magneto-optical cryostat with an applied magnetic field B_0 along the z axis and is mounted in the center of a 10 x 5 mm^2 Helmholtz coil wound from 22 AWG magnet wire. RF radiation is coupled to the coil from the top of the cryostat through an impedance-matched semirigid coaxial transmission line producing an RF magnetic field B_1 along the y axis. The sample growth direction lies in the xz plane and can be rotated to adjust the angle alpha between the growth direction and the laser propagation direction along the x axis. Unless otherwise specified alpha = 10°.

We measure time-resolved FR in a modulation-doped 7.5-nm-wide (110) GaAs QW with a mobility of 1700 cm^2 V^-1 s^-1 and an electron density of 9 x 10^10 cm^-2 at T=300 K. Confinement along the (110) crystal direction suppresses D'yakonov–Perel spin scattering, resulting in spin lifetimes longer than 1 ns from T=5 K to room temperature. A 250-fs 76-MHz Ti:Sapphire laser tuned near the exciton absorption energy (1.572 eV) produces pulses...
that are split into pump and probe with a full width at half maximum (FWHM) of 8 meV and an average power of 2.0 mW and 100 μW, respectively. The linearly (circularly) polarized probe (pump) is modulated by an optical chopper at a frequency \( f_p = 940 \text{ Hz} \) and \( f_c = 3.12 \text{ kHz} \). Both beams are focused on the sample surface to an overlapping spot 50 μm in diameter with the pump beam injecting polarized electron spins along the sample growth direction as shown in Fig. 1(b). The pinning of the initial electron spin polarization \( \vec{S} \) along the growth direction relies on the fact that pump pulses couple predominantly to light hole states, which are split off from light holes states in a QW\(^{13,16} \). Small rotations in the linear polarization of the transmitted probe are measured and are proportional to the component of electron spin polarization in the conduction band along the growth direction. Variation of the pump-probe time delay \( \Delta t \) reveals the time evolution of this spin polarization. In the absence of nuclear polarization, electron spins precess about an axis and at a frequency defined by the Larmor precession vector \( \vec{v}_L = \gamma B_0 \mu_B / h \), where \( \gamma \) is the Landé g factor expressed as a tensor, \( \mu_B \) is the Bohr magneton, and \( h \) is Planck’s constant. GaAs QWs grown in the (110) direction exhibit strong anisotropy in \( \vec{g} \) resulting in both the dependence of \( \vec{v}_L \) on the orientation of \( B_0 \) with respect to the sample’s crystal axes and in a difference between the precession axis \( \vec{v}_L \) and the direction of \( B_0 \).\(^{13} \)

At \( T = 5 \) K, spin-polarized photoexcited electrons generate nuclear spin polarization within the QW through dynamic nuclear polarization (DNP).\(^{1} \) DNP acts through the contact hyperfine interaction, written as \( A_H \vec{S} \cdot \vec{I} = \frac{1}{2} A_H \vec{I} \cdot (\vec{S} \cdot \vec{I}), \) where \( A_H \) is the hyperfine constant and \( \vec{I} \) is the nuclear spin. This “flip-flop” process results in an average nuclear spin \( \langle \vec{I} \rangle \) along \( B_0 \) and is driven by the component of electron spin \( \vec{S} \) in that direction. The sign and magnitude of \( \langle \vec{I} \rangle \) depends on the angle \( \alpha \).

The presence of a nonzero \( \langle \vec{I} \rangle \) in turn acts on the electron spin dynamics through the addition of a term to the precession vector \( \vec{v}_L = \gamma B_0 \mu_B / h + A_H \langle \vec{I} \rangle / h \). The measurement of \( \vec{v}_L \) and the knowledge of \( \gamma \) and \( B_0 \) yield the nuclear polarization frequency \( v_p = A_H \langle \vec{I} \rangle / h \), which has been calculated to be 32.6 GHz for 100% nuclear polarization in GaAs.\(^{4} \) Changes in the average nuclear polarization \( \langle \vec{I} \rangle / \langle \vec{I} \rangle \) within the QW can be measured directly as changes in the precession frequency \( \Delta v_L \).

FR is plotted in Fig. 2(a) as a function of \( \Delta t \) at \( B_0 = 5.3019 \) T with the coil driven continuously at a frequency \( f_c \) set to the \( ^{69}\text{Ga} \) resonance at 50,000 MHz and at two frequencies slightly detuned from resonance. The inset clarifies the reduction of \( v_p \) for the resonant scan in which nuclear spin transitions induced by \( B_1 \) decrease \( \langle \vec{I} \rangle \). Scans with an off-resonant \( f_c \) show the same \( \langle \vec{I} \rangle \) established by DNP without any applied \( B_1 \). Figure 2(b) shows FR data taken under the same conditions as in Fig. 2 while sweeping \( f_c \) across the \( ^{69}\text{Ga} \) resonance at a fixed \( \Delta t = 1932 \) ps. Here, the resonant depolarization of \( \langle \vec{I} \rangle \) and the change in \( v_p \) appear as a peak in the FR signal. The asymmetry of the resonance reflects the fast rate of the frequency sweep with respect to the time required to polarize the nuclei \( T_{\text{DNP}} \approx 90 \) s. In order to investigate the true form of the peak, \( f_c \) is swept across the full nuclear resonance in a time \( T_{\text{sweep}} > T_{\text{DNP}} \). This condition is satisfied for the data shown in Fig. 2(c) where the resonances due to the three isotopes present in the QW, \( ^{69}\text{Ga} \), \( ^{71}\text{Ga} \), and \( ^{73}\text{As} \), appear at the expected frequencies. In addition we observe satellite peaks for each resonance due to the quadrupolar splitting \( 6\Delta Q \). By fitting each resonance to a Gaussian peak and two symmetric satellites, the splittings are measured to be 9.7, 7.0, and 16.3 kHz for the \( ^{69}\text{Ga} \), \( ^{71}\text{Ga} \), and \( ^{73}\text{As} \) isotopes. These values are similar to previously reported measurements and indicate the presence of a small amount of strain on the crystal likely due the wax used in mounting the sample.\(^{17} \) The linewidth (FWHM) of the main resonance is 2.6, 2.1, and 4.6 kHz for the \( ^{69}\text{Ga} \), \( ^{71}\text{Ga} \), and \( ^{73}\text{As} \) isotopes, respectively. The linewidths of the satellite peaks are broader at 9.4, 6.5, and 13.8 kHz probably because of inhomogeneous strain in the sample. As noted elsewhere,\(^{17} \) methods such as ours for accurately measuring \( \Delta Q \) are useful in the determination of built-in strain in semiconductor heterostructures.

The dependence of \( v_p \) on \( \alpha \) is shown in Fig. 2(d) in the case of no RF voltage applied to the transmission line and in the case of a −15 dBm applied at the \( ^{69}\text{Ga} \) resonance \( f_c = 5.0070 \) MHz for \( B_0 = 5.5 \) T. The solid black line is an angle-dependent fit to the data. The dashed line shows FR data taken at \( B_0 = 5.3019 \) T with \( B_1 \) driven at 54.0000 MHz, 50.0400 MHz, and 53.9800 MHz for the red, blue, and green points, respectively. Lines connect the data to guide the eye. (b) FR as a function of \( f_p \) for fixed \( \Delta t = 1932 \) ps as indicated by the dashed line in the inset to (a). (c) FR plotted as a function of detuning \( \Delta f_{\text{NMR}} \) from the \( ^{69}\text{Ga} \) resonance of 52.9539 MHz at \( B_0 = 5.2 \) T, from the \( ^{67}\text{Ga} \) resonance of 67.2898 MHz at \( B_0 = 5.2 \) T, and from the As resonance of 54.4992 MHz at \( B_0 = 7.5 \) T for the gray, red, and green points, respectively. Solid black lines are fits to the data while dashed lines show the three peaks included in those fits. A schematic diagram of the relevant level structure is included in the lower left. (d) \( v_p \) is shown as a function of \( \alpha \) at \( B_0 = 5.5 \) T for no RF voltage applied to the coil and for −15 dBm applied at the \( ^{69}\text{Ga} \) resonance at 56.0070 MHz for the blue and red points, respectively. The solid black line is a fit to the angular dependence of \( v_p \) in the presence of a nonzero \( \langle \vec{I} \rangle \). The dashed black line shows the same dependence with \( \langle \vec{I} \rangle = 0 \).
Depolarization of the resonant isotope within the QW. If \( f_c \) increases, the splitting between resonances increases until at \( f_c = 100 \text{ kHz} \) and \( f_c = 120 \text{ kHz} \), the three resonances are clearly distinguishable.

A calculation of the Hanle effect based on typical bulk GaAs parameters and the three NMR resonances is shown in Fig. 3(b). There is good qualitative agreement between the model and the data allowing us to estimate \( \langle l \rangle / I \approx 0.25\% \) as shown in the dependence predicted by the model in Fig. 3(c). The signal-to-noise in the data indicates that we are sensitive to changes down to 0.05%. Since the region from which we are collecting PL contains \(~ 10^{10} \) nuclei, we estimate a sensitivity of \( 10^{12} \) nuclear spins for this ODNMR technique. In the FR measurement, which was done in a QW, we probed many fewer nuclei, \(~ 10^{10} \). There we could distinguish nuclear polarizations as small as 0.015% corresponding to a sensitivity of \( 10^9 \) nuclear spins.

In conclusion, ODNMR detected by time-resolved FR is an extremely sensitive probe of nuclear polarization capable of resolving small numbers of nuclear spins and distinguishing quadrupolar splittings in the kHz range. It may find use in the determination of built-in strain in GaAs heterostructures and provides an excellent way to perform ODNMR measurements at high magnetic fields, impossible by conventional techniques based on PL polarization.

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References: